

isc N-Channel Mosfet Transistor

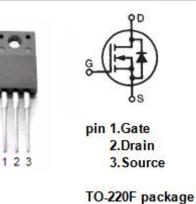
STF12N65M5

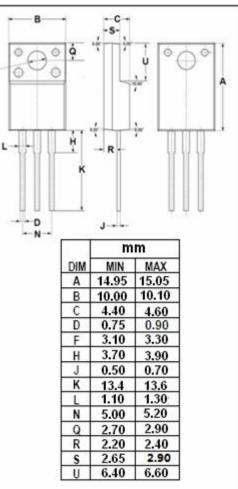
- FEATURES
- Drain Current I_D= 8.5A@ T_C=25℃
- · Drain Source Voltage-
 - : V_{DSS}=650V(Min)
- · Fast Switching Speed
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

· Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT	- B-		
V _{DSS}	Drain-Source Voltage	650	v	₽ ⊖⊖		
V _{GS}	Gate-Source Voltage	±25	V			
ID	Drain Current-continuous@ T _c =25°C	8.5	А	⊾-{;} {, ,		
Ідм	Pulse Drain Current	34	А	D		
P _{tot}	Total Dissipation@T _c =25℃	25	W	- N -		
Tj	Max. Operating Junction Temperature	150	°C			
T _{stg}	Storage Temperature Range	-55~150	°C			
• THERMA	AL CHARACTERISTICS					
SYMBOL	PARAMETER	МАХ	UNIT			





isc website: www.iscsemi.com

R_{th j-c}

Thermal Resistance, Junction to Case

isc & iscsemi is registered trademark

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°C/W



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT	
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	650			V	
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250µA	3		5	V	
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 4.3A			430	mΩ	
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} = 0			±100	nA	
IDSS	Zero Gate Voltage Drain Current	V _{DS} = Max rating			1	μA	
		V _{DS} = Max rating; T _C =125℃			100		
V _{SD}	Diode Forward On-Voltage	I _S = 8.5A ;V _{GS} = 0			1.5	V	

NOTICE:

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